Evidence for a delocalization quantum phase transition without symmetry breaking in CeCoIn₅

Nikola Maksimovic^{1,2*}, Daniel H. Eilbott^{1,2}, Tessa Cookmeyer^{1,2}, Fanghui Wan^{1,2}, Jan Rusz⁵, Vikram Nagarajan^{1,2}, Shannon C. Haley^{1,2}, Eran Maniv^{1,2}, Amanda Gong^{1,2}, Stefano Faubel^{1,2}, Ian M. Hayes^{1,2}, Ali Bangura⁴, John Singleton³, Johanna C. Palmstrom³, Laurel Winter³, Ross McDonald³, Sooyoung Jang^{1,2}, Ping Ai², Yi Lin², Samuel Ciocys^{1,2}, Jacob Gobbo^{1,2}, Yochai Werman^{1,2}, Peter M. Oppeneer⁵, Ehud Altman^{1,2}, Alessandra Lanzara^{1,2}, James G. Analytis^{1,2*}

¹Department of Physics, University of California, Berkeley, Berkeley, CA 94720, USA. ²Materials Sciences Division, Lawrence Berkeley National Laboratory, Berkeley, CA 94720, USA. ³National High Magnetic Field Laboratory, Los Alamos, NM 97545, USA. ⁴National High Magnetic Field Laboratory, Tallahassee, FL 32310, USA. ⁵Department of Physics and Astronomy, Uppsala University, Box 516, S-75120 Uppsala, Sweden.

*Corresponding author. Email: nikola_maksimovic@berkeley.edu (N.M.); analytis@berkeley.edu (J.G.A.)

The study of quantum phase transitions that are not clearly associated with a broken symmetry is a major effort in condensed matter physics, particularly in the problem of high-temperature superconductivity where such transitions are thought to underlie the mechanism of superconductivity itself. In this study, we argue that the putative quantum critical point in the prototypical unconventional superconductor CeCoIn₅ is characterized by the delocalization of electrons in a transition that connect two Fermi surfaces of different volumes, with no apparent broken symmetry. Drawing on established theory of *f*-electron metals, we discuss an interpretation for such a transition that involves the fractionalization of spin and charge, a model which well-describes the anomalous transport behavior we measure in the Hall effect.

CeCoIn₅ is an *f*-electron metal with notable similarities to high-temperature superconducting copper-oxides, for example in crystal structure, transport properties, and unconventional superconductivity (1-10). Both sets of materials also exhibit signatures of a quantum phase transition (QPT), a phase transition induced by a non-thermal parameter, underlying the superconducting state. However, in many unconventional superconductors, it is unclear whether the underlying QPT can be understood in the conventional sense as separating phases with different symmetries. An exploration of unconventional types of QPTs, non-symmetry breaking (11) or weakly symmetry breaking (12, 13), has therefore become a subject of intense study. In this work, we bring evidence that CeCoIn₅ is proximate to a quantum phase transition where the density of itinerant electrons changes apparently without breaking of symmetry. Established theory of *f*-electron metals provides a route to interpret such a transition.

At the microscopic level, *f*-electron metals such as $CeCoIn_5$ are described by a Kondo lattice model. Each cerium atom hosts a single *f* level valence electron which contributes a localized spin-1/2 moment. These local moments coexist with a sea of itinerant conduction electrons. In the conventional metallic ground state of the Kondo lattice, the *f*-electrons appear to become an integral part of the itinerant metal. In particular, they join the conduction electrons, contributing their full share to the total Fermi volume as prescribed by Luttinger's theorem (14). This phenomenon occurs through the formation of Kondo singlet correlations between the local *f* moments and the conduction electrons, which effectively hybridize the f level with the conduction bands.

A long-standing challenge has been to characterize a QPT in which the *f*-electrons recover their localized character and withdraw from the itinerant Fermi volume. Superficially, the remaining Fermi volume without *f*-electrons is in apparent violation of Luttinger's theorem. The loss of Fermi volume when *f*-electrons localize is therefore conventionally accompanied by a transition to a (antiferromagnetic) spin-density wave state, whereby Luttinger's theorem is recovered in the appropriately folded Brillouin zone associated with translational symmetry breaking (*15–19*). In this paper, we present Hall effect, quantum oscillation, and angle-resolved photoemission spectroscopy (ARPES) measurements of CeCoIn₅ with small levels of chemical substitution, and compare the experimental data to ab initio calculations. We find evidence for an *f*-electron delocalization QPT without symmetry breaking.

Figure 1A presents low-temperature measurements of the Hall resistivity, ρ_{xy} , versus magnetic field, *H*, for CeCoIn₅ samples with varying levels of cadmium (hole-doping) or tin (electron-doping), both of which substitute indium. The Hall coefficient, $R_H = \rho_{xy} / \mu_0 H$ can be used to estimate the net carrier density enclosed by the Fermi surface according to the formula (20)

$$n_{net} = \frac{1}{eR_H \left(H \to \infty\right)} \tag{1}$$

where n_{net} is the net carrier density-electrons minus holes. In multiple band metals such as CeCoIn₅, Eq. 1 only applies in the limit where high fields eliminate the effects of carrier mobility misbalances and R_H becomes field-independent (see (21) Section 3 for more details on the high-field limit). For each sample, we measure the high-field value of R_H at 0.5 K in order to approximate the net carrier density. Many of the traces shown in Fig. 1A appear to saturate at high fields, and fig. S4 (21) shows that evaluation of the high-field slope of ρ_{xy} is in good agreement with the high-field value of $\rho_w / \mu_0 H$, suggesting that at these temperatures and fields the Hall coefficient is close to field-independent. In addition, select samples were measured in pulsed magnetic fields up to 75 T, as shown in Fig. 1B, where the Hall coefficient is fieldindependent over an extended field range; the extracted Hall coefficients from pulsed and continuous fields are in good agreement for these samples (Fig. 1C). Finally, our Hall coefficient measurements on pure CeCoIn₅ agree well with measurements at 20 mK where the Hall resistivity is completely linear in field (22). These facts together give confidence that our extracted Hall coefficient values can be interpreted as an approximate measurement of the net carrier density as described by Eq. 1.

Figure 1C shows the value of $1/eR_H$, approximating the net carrier density, extracted for samples with different levels of chemical substitution in continuous and pulsed magnetic fields. The carrier density of this material excluding the felectron can be established using Hall resistivity measurements of LaCoIn₅ shown in Fig. 1B (its Hall coefficient is fieldindependent above 5 T at 1.8 K. See also fig. S3 (21)); LaCoIn₅ can be thought of as CeCoIn₅ without the *f*-electron. We find that the Hall coefficient of CeCoIn₅, evaluated either up to 60 Tesla or up to 14 Tesla at 0.5 K, is close to that of LaCoIn₅ (Fig. 1C). This suggests that the two materials have similar net carrier densities, implying that the f-electrons are close to localized in CeCoIn₅. With cadmium-substitution $1/eR_H$ remains close to that of LaCoIn₅, but with tin substitution increases to a value consistent with the addition of one itinerant electron per unit cell. Identifying the additional electron as the single cerium f-electron suggests that Sn-substitution induces a delocalization transition of the *f*-electrons. None of these samples show a finite-temperature phase transition other than superconductivity. Only in Cd substitution levels higher than 0.6% is an antiferromagnetic phase observed (fig. S1 (21)) (23). In addition, the specific heat capacity at moderate temperature remains constant across this substitution series (Fig. 1C); we will comment more on this later.

When the *f*-electrons delocalize, the Fermi surfaces are expected to reconstruct and increase in volume. The results of our density functional theory (DFT) calculations of the three Fermi surfaces comparing the (de)localized *f*-electron models

are visualized in Fig. 2A (DFT calculation details are provided in (21) Section 1). In summary, according to the calculation felectron delocalization causes the extended γ surface to disconnect into small ellipsoidal pockets at the Brillouin zone center and edge, and the γ pocket at the zone top (γ_Z) to disappear. Also, large extended surfaces α_Z and β_Z appear at the zone top, and the α and β cylinders expand slightly. In pure CeCoIn₅, previous angle-resolved photoemission (ARPES) data at 10-20 K are in better qualitative agreement with the localized *f*-electron model as α_Z and β_Z are absent, and γ_Z is present (24, 25). However, the volumes of the α and β cylinders are slightly larger than those of the localized model (24-26), and the smaller γ Fermi surface seems to exhibit features of both the delocalized and localized models, being potentially disconnected (suggesting delocalized) but retaining γ_Z (suggesting localized) (24, 25, 27, 28). These characteristics may point to a partially delocalized *f*-electron character in pure CeCoIn₅. This interpretation is also promoted by previous magnetic resonance (29) and photoemission studies (24,30, 31). Note that our Hall effect measurements suggest that the f-electrons only weakly contribute to the Fermi volume of CeCoIn₅ even at 0.5 K, consistent with partially localized *f*electrons in the low-temperature limit.

De Haas-van Alphen (dHvA) oscillations measure extremal areas of the Fermi surface perpendicular to the field direction, giving a probe of the Fermi surface structure at extremely low temperature. Here we compare our dHvA measurements of Sn-doped CeCoIn₅ and published data on pure CeCoIn₅ (5). As seen in Table 1 and Fig. 1C, the sizes of the α and β cylinder orbits in pure CeCoIn₅ are more consistent with the delocalized model, implying that *f*-electrons incorporate into these Fermi surface sheets. However, there do not appear to be additional frequencies associated with the α_Z and β_Z sheets of the delocalized model, and orbit β_2 increases as a function of tilt angle away from [001] (Fig. 2C), further suggesting that the β cylinder is fully connected in better qualitative agreement with the localized model. In the Sn-substituted sample, the sizes of the α and β cylinders change slightly compared to pure CeCoIn₅ (Table 1). In addition, an oscillation of about 16 kT appears for two field angles near [001]. This oscillation does not appear to be harmonically related to the α_{1-3} branches, and its frequency and angledependence agree well with a predicted orbit on α_Z of our delocalized model calculations. Furthermore, 1.2 kT and 2 kT frequencies for field angles near [001] are indicative of holes in the β cylinder (Fig. 2A), and, a branch of the β_2 cylinder orbit appears to decrease as a function of tilt angle from [001] in better agreement with the delocalized model (Fig. 1C), further suggesting that holes develop in the β cylinder. Finally, possible low frequency oscillations <800 T at several angles, which seem to be present in pure CeCoIn₅ over certain angular ranges as well, are most naturally assigned to small

 γ -ellipsoids (Fig. 2C), but could also originate from the γ_Z sheet. Table 1 summarizes the frequency assignments based on comparison to DFT calculations, which suggests that the α_Z and β_Z sheets are present in the Fermi surface of the Sn-substituted sample. From dHvA, it is not possible to conclusively say whether these sheets are absent in pure CeCoIn₅ at low temperature because the orbit frequencies on α_Z and β_Z are sensitive to the precise structure of these Fermi surfaces. Nevertheless, the comparison shown in Table 1 is indicative of a Fermi surface reconstruction induced by Sn-substitution.

Our ARPES measurements corroborate the dHvA evidence for a Fermi surface reconstruction. Figure 3 compares Fermi surface maps at the Brillouin zone top in pure CeCoIn₅ and 3% Sn-substituted CeCoIn₅ at 10 K (additional data are provided in (21) Section 9). Our data on pure CeCoIn₅ agrees well with previous reports. The cylindrical Fermi surfaces centered at the zone corners are visible. Bright spots near the Z point are probably signatures of the γ_Z Fermi surface, as discussed in Refs. (27, 31). In the 3% Sn-substituted sample, we observe enhanced intensity at the R point of the Brillouin zone relative to the pure material, as well as a qualitative change in structure near Z. Overall it appears that the electronic structure changes with Sn-substitution, with a sharp cross-shaped structure emerging in the RZA plane which resembles α_z or β_z of our delocalized model calculations (α and β bands nearly overlap along this cut, and as such they may be difficult to distinguish from one another in ARPES). Weak features appear at the R point in pure CeCoIn₅ as well, potentially indicating that incoherent states exist at the R pointthese states may exist because of the partially delocalized felectron character in the pure material. In Fig. 3C, we explore the temperature-dependence of these Fermi surface sheets via the ARPES intensity at the R point. The relative intensity at R increases in the Sn-substituted sample upon decreasing temperature below about 90 K with the onset of f/conduction hybridization (see also fig. S16 (21)). In the pure material, the R point spectral weight is relatively constant down to 10 K. This comparison suggests that the Fermi surface sheet in 3% Sn-doped CeCoIn₅ emerges, or is made relatively more coherent, because of enhanced f/conduction electron hybridization induced by Sn-substitution.

One way to view *f*-electron delocalization is as a result of Kondo hybridization between the *f* level and conduction electrons. Although there are reports of hybridization developing below about 45 Kelvin in pure CeCoIn₅ (*27*) and Cd-doped Ce-CoIn₅ (*32*) resulting in a detectable *f*-electron contribution to the Fermi surface, we find that the low-temperature carrier density of these materials is consistent with predominantly localized *f*-electrons (Fig. 1). In contrast to the pure material, the net carrier density of Sn-substituted samples appears to include the *f*-electrons (Fig. 1C). This change coincides with signatures of new Fermi surface sheets (Fig. 3 and Table 1),

which seem to agree well with predicted Fermi surfaces unique to the delocalized *f*-electron DFT model (Fig. 2A). Taken together, these data suggest that Sn-substitution of Ce-CoIn₅ induces a Fermi volume changing transition between a phase with predominantly localized *f*-electrons to one with a delocalized character. This transition could be attributed to an enhancement of the Kondo coupling induced by electron doping (25, 33, 34). High magnetic fields may compete with the Kondo coupling by polarizing the *f*-electrons, but notably the Hall resistivity remains linear up to 73 T (Fig. 1B), so it seems likely that higher fields are required to induce a complete breakdown of Kondo hybridization.

A delocalization transition is a reasonable scenario from the perspective of doping-tuned Kondo coupling. Because of the constraints imposed by Luttinger's theorem, the reduction in Fermi volume in the more localized *f*-electron regime is expected to coincide with antiferromagnetic order where the Brillouin zone is reduced (15). It is however hard to reconcile this scenario with the data because the transition to antiferromagnetism is seen only around Cd doping of 0.6% (23), considerably removed from the suggested delocalization transition induced by Sn-substitution (Fig. 1C). Furthermore, magnetic order has never been observed in native CeCoIn₅ or Sn-substituted CeCoIn₅ (6, 25, 33, 34), and the ARPES and dHvA data suggest that the Brillouin zone is essentially unchanged by Sn-substitution. An alternative possibility is the formation of a fractionalized phase in the more localized *f*electron regime (11). In this theoretically predicted phase, the f-electron charge localizes to the cerium site, reducing the Fermi volume, while the spin excitations of the *f* moments remain itinerant and form a charge neutral Fermi surface (11). We can speculate that the specific heat remains constant across the substitution series (Fig. 1C) owing to the presence of such a neutral Fermi surface, which conserves the fermionic degrees of freedom of the system even when the density of itinerant electrons appears to increase. One may also expect quantum fluctuations associated with a delocalization transition to enhance the specific heat coefficient. Such an enhancement has been observed as a function of decreasing temperature below 2 K in pure $CeCoIn_5(2)$. The confinement of these effects to <2 K temperatures could explain why we do not detect singular behavior in C/T at 4 K across the substitution series.

Our calculations of the Hall conductivity of such a fractionalized phase capture several distinctive aspects of the low-field Hall coefficient in this material. In the simplest description of the fractionalized Fermi liquid, the *f*-electron separates into a fermionic spinon carrying its spin, and a gapped bosonic mode, in this case a valence fluctuation, carrying its charge. *f*-electron delocalization can be identified with the closing of the boson gap. Near this transition, the electrical conductivity has contributions from the fermionic spinons, the charged bosons and the conduction electrons. The spinon and the bosons should be added in series (*35*). The boson's resistivity will then dominate owing to their much smaller number, and we therefore neglect the spinon contribution. Adding to this the resistivity of the conduction band in parallel gives:

$$R_{H} = R_{H}^{c} \frac{\sigma_{c}^{2}}{(\sigma_{\text{tot}})^{2}} + \frac{1}{\mu_{0}H} \frac{\sigma_{xy}^{b}}{(\sigma_{\text{tot}})^{2}}$$
(2)

where σ_c and R_H^c are the longitudinal conductivity and Hall coefficient of the conduction electrons, respectively, and σ_{vv}^{b} is the Hall conductivity of the bosonic valence fluctuations. The total conductivity is $\,\sigma_{_{
m tot}}$. In our calculation, we consider two processes that contribute to the scattering rate of the valence fluctuations. One process is provided by the internal gauge field (11). The other mechanism is scattering on the doped ions, which grows linearly with the doping level (see fig. S5 (21)). One may expect an enhancement of the low-field Hall coefficient stemming from the second term in Eq. 2 caused by the singular behavior of the valence fluctuations when the boson gap closes. This expectation is corroborated by a semi-classical Boltzmann analysis, the details of which are given in (21) Section 7. As shown in Fig. 4, the results of the calculation of the conductivity in this model give good agreement with the measured Hall coefficient as a function of temperature, doping level, and magnetic field with the assumption that pure CeCoIn₅ is the sample closest to the delocalization transition. The results shown in Fig. 4B are obtained from a calculation of σ_{xy}^{b} , and converted to a Hall coefficient using the physical resistivity of the system $1/\sigma_{tot} = \rho_{xx} \sim T$ as observed in the experiment over the relevant temperature range. A more complete description of the longitudinal resistivity in this model will be the subject of future work.

We emphasize that the experimental observations seen in Fig. 4 are difficult to reconcile with more conventional transport models. From the point of view of band theory, the low-field R_H is proportional to the carrier density of the most mobile carriers (20), so it is surprising that R_H has such a strong temperature-dependence with a peak at finite temperature, and retains the same sign and uniformly decreases with either hole or electron doping. In addition, the observed symmetric-in-doping Hall coefficient cannot be readily attributed to disorder scattering induced by substitution, as we find that disordering the material by other means, substituting lanthanum for cerium, has a relatively small effect on the low-field R_H (see fig. S6 (21)). These key features of the experimental transport data are captured by the valence fluctuation model described above.

The present study provides evidence that $CeCoIn_5$ exists near a quantum phase transition associated with the

delocalization of *f*-electron charge. The absence of evidence for symmetry breaking around this transition opens the possibility for the fractionalization of *f*-electrons into separate spin and charge degrees of freedom. Although our conductivity calculations support this theoretical picture, direct evidence for such fractionalized electrons is desirable, and may be possible with inelastic neutron measurements (36) or Josephson tunneling experiments (37). On a final note, recent experiments on cuprate high-temperature superconductors find evidence for a Fermi surface reconstruction where the localized charge of the Mott insulator gradually delocalizes over a certain oxygen doping range near the endpoint of the pseudogap phase (sometimes referred to as a p to 1+p transition (38)). We have presented evidence for an analogous transition in an *f*-electron metal. It is possible that such a quantum phase transition underlies some of the similarities between $CeCoIn_5$ and cuprate superconductors (1-9), and perhaps our work may help guide interpretation of these recent results on cuprates.

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performed dilution fridge measurements. J.S., J.C.P., L.W., and R.M. performed pulsed field measurements. D.H.E., P.A, Y.L, S.C, and J.G. performed ARPES measurements. All authors contributed to writing the manuscript. **Competing interests:** The authors declare no competing financial interests. **Data and materials availability:** All data provided in this report are publicly available: https://osf.io/dfm7x/ (39).

SUPPLEMENTARY MATERIALS

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Table 1. de Haas-van Alphen extremal orbit assignments. Units of kiloTesla, H || [001], from experiments and DFT calculations. Each orbit is labeled by the assigned Fermi surface sheet, which are visualized on the calculated Fermi surface sheets in Fig. 2A.

Fermi surface	dHvA orbit labe	l localized <i>f-</i> elec- tron model	CeCoIn₅ Ref. (<i>5</i>)	0.33% Sn- doped CeCoIn₅	delocalized <i>f-</i> electron model
γz	γ_1	0.8			
γz	γ2	2.3			
γ-cross	γз	13.2			
γ-ellipsoid	γ4			(0.46)	0.7
γ-ellipsoid	γ5		(0.24)	(0.2)	0.22
α-cylinder	α_1	4.8	5.6	5.4	5.6
α-cylinder	α2	4.0	4.5	4.8	4.4
α-cylinder	α ₃	3.9	4.2	4.4	4.3
αz	α4			16.3	15.8
β-cylinder	β_1	10.3	12.0	11.9	12.3
β-cylinder	β2	6.1	7.5	6.8	6.7
βz/cylinder	β3			2.0	1.6
β_Z /cylinder	β4			1.2	0.9



Fig. 1. Carrier density measurements in doped CeCoIn₅. (A) Hall coefficient as a function of field in doped CeCoIn₅ with Cd concentrations 0.2% and 0.4%, and Sn concentrations 0.11%, 0.22%, 0.33%, 0.44%, 1.2%, 1.39%, 1.65%, 1.9%, and 3.3%. As discussed in the main text, the inverse of the Hall coefficient $(\rho_{xy} / \mu_0 H)$ in

the high-field limit can be used to approximate the net carrier density (see also (*21*) Section 4). Gray lines denote the high-field Hall coefficient of the non-*f* analog LaColn₅ and the calculated value including one additional electron per unit cell. (**B**) Pulsed field Hall resistivity of CeColn₅ (T = 0.66 K) and Sn-doped CeColn₅ (T = 0.5 K) overlaid on the continuous field Hall resistivity of LaColn₅ (1.8 K). (**C**) Inverse high-field Hall coefficient of CeColn₅ at 0.5 K as a function of doping level, including measurements in continuous field up to 14 T or 18 T (filled circles) and pulsed field up to 73 T (open circles). With Sn-substitution, the apparent carrier density of CeColn₅ increases by about one electron per unit cell above that of LaColn₅. This trend provides evidence that Sn-substitution delocalizes the single cerium *f*-electron per unit cell in CeColn₅. The value of $1/eR_H$ in some Sn-doped samples lies above the calculated +1 electron line, likely because the Hall coefficient has not completely saturated in these samples at 14 T. At higher fields the value of $1/eR_H$ seems to saturate at the +1 electron value as seen in the 1.6% Sn-doped sample at 70 T. The lower panel shows the 4 Kelvin heat capacity (units of mJ/mol K²) across this doping series.



Fig. 2. de Haas-van Alphen oscillations in Sn-doped CeCoIn₅ and comparison to DFT calculations. (A) DFT calculated Fermi surface sheets of CeCoIn₅ with localized and delocalized *f*-electron models. Predicted dHvA orbits for $H \parallel [001]$ are drawn in black and red. Red orbits are unique to the delocalized *f*-electron model. (B) Characteristic dHvA spectrum with the magnetic field 4.8° away from [001] of a crystal of 0.33% Sn-doped CeCoIn₅. The inset shows oscillations in the magnetic torque after background subtraction. (C) dHvA oscillation frequencies as a function of angle tilting the magnetic field from the crystallographic [001] to [100] directions in pure CeCoIn₅ (Ref. (5)) and 0.33% Sn-doped CeCoIn₅. Light green points are DFT calculated frequencies of the localized *f*-electron models respectively.



Fig. 3. ARPES measurements of CeCoIn⁵ **and Sn-doped CeCoIn**⁵. (**A**) Fermi surface maps in pure and 3% Sn-substituted CeCoIn⁵ at the Brillouin zone top (RZA plane). A new Fermi surface sheet appears at the zone top in the Sn-substituted sample. Each of the four subpanels represents measurements on a different cleave. (**B**) A-R-A dispersion cuts. Parabolic α and β bands are labeled by red and blue dotted lines. The new Fermi surface in the Sn-substituted sample is observed as an increase in spectral intensity at the Fermi level at R. The spectral intensity within the white box has been enhanced by a factor of ten for clarity. (**C**) Comparison of temperature-dependent intensity at the R point normalized to the average value between 120-160 K.

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Fig. 4. Comparison of experimental data and theoretical calculations of the conductivity of critical valence fluctuations around an *f*-electron delocalization transition. (A) Experimentally measured Hall resistivity, divided by the applied magnetic field, for samples with different compositions. (B) The theoretically predicted Hall effect from bosonic valence fluctuations of the fractionalized Fermi liquid model. Each panel is labeled by the chemical potential in the theory corresponding to the doping level in the experiment, where $\mu < 0$ corresponds to hole-doping and $\mu > 0$ corresponds to electron-doping. Curves are labeled by the normalized magnetic field value and all theory data includes a parametrization of impurity scattering, $\overline{C} = 4$. See Supplement S7 (21) for the details of the calculation and relevant parameter normalizations.



Evidence for a delocalization quantum phase transition without symmetry breaking in CeCoIn

Nikola MaksimovicDaniel H. EilbottTessa CookmeyerFanghui WanJan RuszVikram NagarajanShannon C. HaleyEran ManivAmanda GongStefano Faubellan M. HayesAli BanguraJohn SingletonJohanna C. PalmstromLaurel WinterRoss McDonaldSooyoung JangPing AiYi LinSamuel CiocysJacob GobboYochai WermanPeter M. OppeneerEhud AltmanAlessandra LanzaraJames G. Analytis

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